

GENERAL DESCRIPTION

OB2354 combines a dedicated current mode PWM controller with a high voltage power MOSFET. It is optimized for high performance, low standby power, and cost effective off-line flyback converter applications in sub 20W range.

OB2354 offers complete protection coverage with automatic self-recovery feature including Cycle-by-Cycle current limiting (OCP), over load protection (OLP), VDD over voltage clamp and under voltage lockout (UVLO). Excellent EMI performance is achieved with On-Bright proprietary frequency shuffling technique together with soft switching control at the totem pole gate drive output.

The tone energy at below 20KHZ is minimized in the design and audio noise is eliminated during operation. OB2354 is offered in DIP8 package.

FEATURES

- Power on Soft Start Reducing MOSFET Vds Stress
- Frequency shuffling for EMI
- Extended Burst Mode Control For Improved Efficiency and Minimum Standby Power Design
- Audio Noise Free Operation

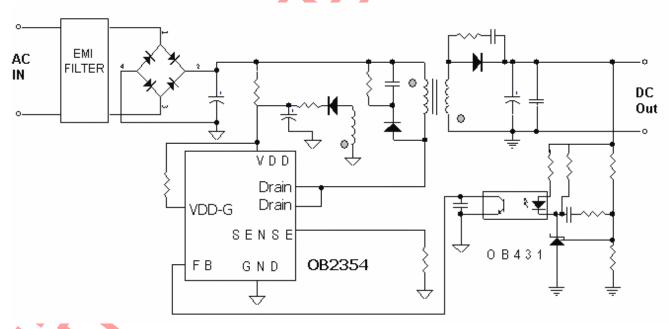
TYPICAL APPLICATION

- Fixed 50KHZ Switching Frequency
- Internal Synchronized Slope Compensation
- Low VDD Startup Current and Low Operating Current
- Leading Edge Blanking on Current Sense Input
- Good Protection Coverage With Auto Self-Recovery
 - VDD Over Voltage Clamp and Under Voltage Lockout with Hysteresis (UVLO)
 - On-Bright Proprietary Line Input Compensated Cycle-by-Cycle Over-current Threshold Setting For Constant Output Power Limiting Over Universal Input Voltage Range.
 - Overload Protection (OLP).
 - Over voltage Protection(OVP)

APPLICATIONS

Offline AC/DC flyback converter for

- Battery Charger
- PDA power supplies
- Digital Cameras and Camcorder Adaptor
- VCR, SVR, STB, DVD&DVCD Player SMPS
- Set-Top Box Power
- Auxiliary Power Supply for PC and Server
 - Open-frame SMPS



Output Power Table

	Product	230VAC±15%	85-265VAC
	Product	Open Frame¹	Open Frame ¹
	OB2354	21W	16W

Notes:

1.

Maximum practical continuous power in an open frame design with sufficient drain pattern as a heat sink, at 50°C ambient.

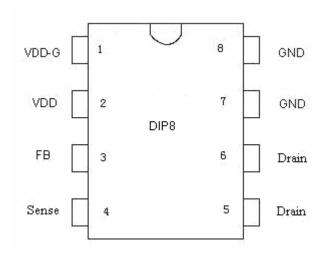
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GENERAL INFORMATION

Pin Configuration

The OB2354 is offered in DIP8 package as shown below.



Ordering Information

Part Number	Description
OB2354AP	DIP8, Pb-free

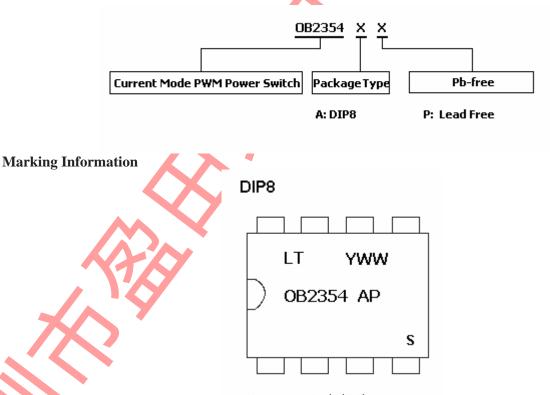
Package Dissipation Rating

Package	RθJA (℃/₩)
DIP8	75
Note: Drain Pin Connected to 100mm2 P	CB copper clad.

Absolute Maximum Datings

Absolute Maximum Ratings						
Parameter	Value					
Drain Voltage (off state)	-0.3V to 650V					
VDD Voltage	-0.3V to 30 V					
VDD-G Input Voltage	-0.3V to 30 V					
VDD Clamp Continuous	10mA					
Current						
FB Input Voltage	-0.3 to 7V					
Sense Input Voltage	-0.3 to 7V					
Min/Max Operating Junction	-20 to 150°C					
Temperature T _J						
Min/Max Storage Temperature	-55 to 160℃					
T _{stg}						
Lead Temperature (Soldering,	260°C					
10secs)						

Note: Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute maximum-rated conditions for extended periods may affect device reliability.



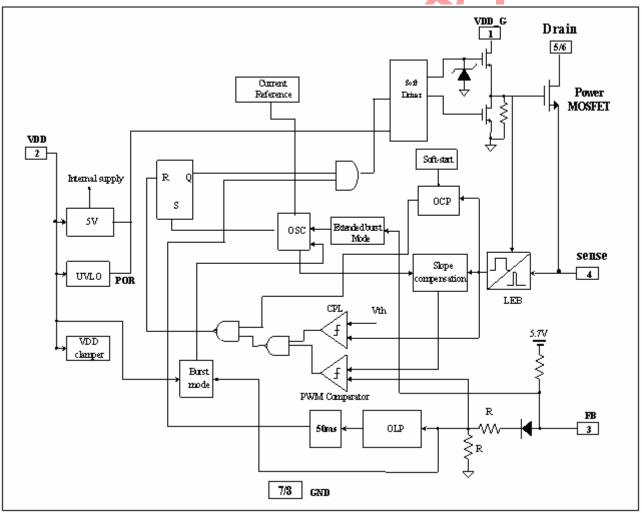
- Y: Year Code(0-9) WW: Week Code (01-52)
- A: Package Code for DIP8
- P: Pb-free
 - S: Internal Code(Optional)



TERMINAL ASSIGNMENTS

Pin Name	I/O	Description
GND	Р	Ground
FB	Ι	Feedback input pin. The PWM duty cycle is determined by voltage level into this pin and the current-sense signal at Pin 4.
VDD-G	Р	Internal Gate Driver Power Supply
SENSE	Ι	Current sense input
VDD	Р	IC DC power supply Input
Drain	0	HV MOSFET Drain Pin. The Drain pin is connected to the primary lead of the
		transformer

BLOCK DIAGRAM





ELECTRICAL CHARACTERISTICS

 $(T_A = 25^{\circ}C, VDD = 16V, \text{ if not otherwise noted})$

Symbol	Parameter	Test Conditions	Min	Тур	Max	Unit
Supply Voltage (V				_		
Istartup	VDD Start up	VDD=14.5V,Measure		5	20	uA
	Current	Leakage current into VDD				
I_VDD_Operation	Operation Current	V _{FB} =3V		1.6		mA
UVLO(ON)	VDD Under		8.7	9.7	10.7	V
	Voltage Lockout				K	
	Enter					
UVLO(OFF)	VDD Under		14.6	15.8	17.0	V
	Voltage Lockout					
	Exit (Recovery)					
OVP(ON)	Over voltage	CS=0V,FB=3V	27.0	28.5	30.0	V
()	protection	Ramp up VDD until gate				
	voltage	clock is off				
VDD Clamp	VDD Zener Clamp	$I_{DD} = 10 \text{ mA}$		30		V
, 22_ciump	Voltage			20		
Feedback Input Se				1	1	1
V _{FB} Open	V _{FB} Open Loop		5.4	5.7	6.0	V
· ^{LR} OPOI	Voltage		5.7	5.7	0.0	
I _{FB} _Short	FB pin short	Short FB pin to GND and		1.45		mA
TLR_DHOIL	circuit current	measure current		1.75		111/ 1
V _{TH} 0D	Zero Duty Cycle			0.8		V
VTH_OD	FB Threshold			0.0		v
	Voltage					
V _{TH} _PL	Power Limiting			3.7		V
VIH_IL	FB Threshold			5.7		v
	Voltage					
T _D _PL	Power limiting			50		mSec
	Debounce Time			50		mote
Z _{FB} IN	Input Impedance			4		Kohm
Current Sense Inp				-		Komm
Soft start time				4		ms
	Looding edge			270		
T_blanking	Leading edge blanking time			270		ns
Z _{SENSE} _IN	Input Impedance		1	40	<u> </u>	Kohm
	Over Current	From Over Current Occurs		120		nSec
T _D OC	Detection and	till the Gatedrive output start		120		nsec
	Control Delay	to turn off				
V OC	Internal Current	FB=3.3V	0.72	0.77	0.82	V
V _{TH} _OC		TD-3.3 V	0.72	0.77	0.82	v
	Limiting Threshold Voltage					
Oscillator	Theshold voltage	1	I	l		l
Uscillator						
F _{osc}	Normal Oscillation		45	50	55	KHZ
	Frequency					
∆f Temp	Frequency			5		%
	Temperature			-		
	Stability					
	····· · · · · · · · · · · · · · · · ·	1	1	1	1	1



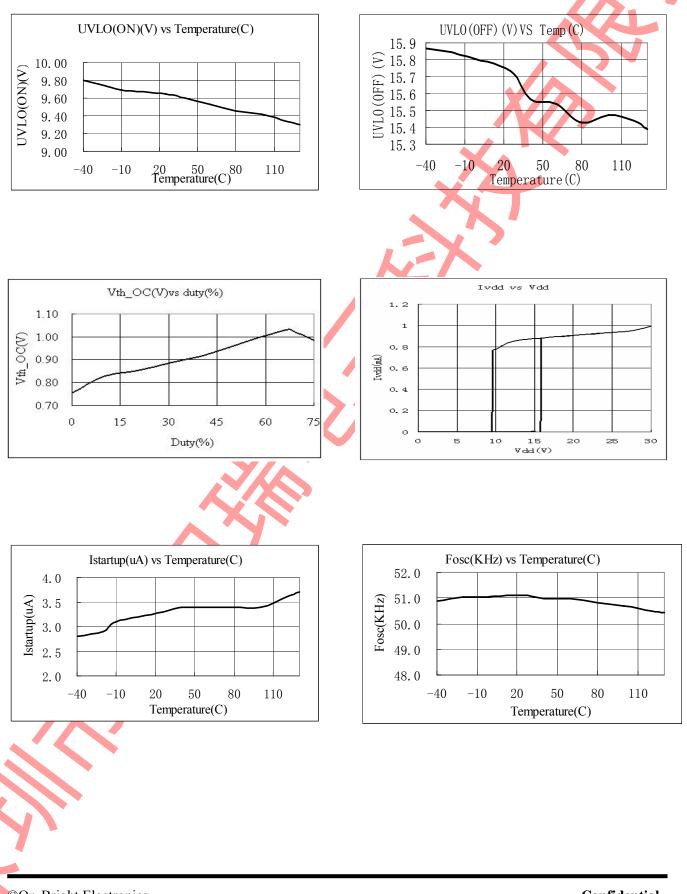
Δf_VDD	Frequency Voltage Stability			5		%
D_max	Maximum duty cycle	FB=3.3V, CS =0V	70	80	90	%
F_Burst	Burst Mode Base Frequency			22	$\boldsymbol{\Lambda}$	KHZ
Mosfet Section	1					
BVdss	MOSFET Drain- Source Breakdown Voltage			650	シ	V
RDS(on)	Static Drain to Source On Resistance		7	9	11	Ω
Frequency Sh	uffling					
Δf_OSC	Frequency Modulation range /Base frequency		-4	1	4	%



Current Mode PWM Power Switch ^{Freq Shuffling}

CHARACTERIZATION PLOTS

(The characteristic graphs are normalized at Ta=25°C)



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OPERATION DESCRIPTION

The OB2354 is a low power off-line SMPS Switcher optimized for off-line flyback converter applications in sub 20W power range. The 'Extended burst mode' control greatly reduces the standby power consumption and helps the design easily to meet the international power conservation requirements.

• Startup Current and Start up Control

Startup current of OB2354 is designed to be very low so that VDD could be charged up above UVLO threshold level and device starts up quickly. A large value startup resistor can therefore be used to minimize the power loss yet achieve a reliable startup in application. For AC/DC adaptor with universal input range design, a 2 M Ω , 1/8 W startup resistor could be used together with a VDD capacitor to provide a fast startup and yet low power dissipation design solution.

• Operating Current

The Operating current of OB2354 is low at 2mA. Good efficiency is achieved with OB2354 low operating current together with the 'Extended burst mode' control features.

Soft Start

OB2354 features an internal 4ms soft start to soften the electrical stress occurring in the power supply during startup. It is activated during the power on sequence. As soon as VDD reaches UVLO(OFF), the peak current is gradually increased from nearly zero to the maximum level of 0.77V. Every restart up is followed by a soft start.

• Frequency shuffling for EMI improvement

The frequency Shuffling (switching frequency modulation) is implemented in OB2354. The oscillation frequency is modulated so that the tone energy is spread out. The spread spectrum minimizes the conduction band EMI and therefore eases the system design.

Extended Burst Mode Operation

At light load or zero load condition, most of the power dissipation in a switching mode power supply is from switching loss on the mosfet, the core loss of the transformer and the loss on the snubber circuit. The magnitude of power loss is in proportion to the switching frequency. Lower switching frequency leads to the reduction on the power loss and thus conserves the energy. The switching frequency is internally adjusted at no load or light load condition. The switch frequency reduces at light/no load condition to improve the conversion efficiency. At light load or no load condition, the FB input drops below burst mode threshold level and device enters Burst Mode control. The Gate drive output switches only when VDD voltage drops below a preset level and FB input is active to output an on state. Otherwise the gate drive remains at off state to minimize the switching loss and reduces the standby power consumption to the greatest extend.

The switching frequency control also eliminates the audio noise at any loading conditions.

Oscillator Operation

The switching frequency of OB2354 is internally fixed at 50KHZ. No external frequency setting components are required for PCB design simplification.

• **Current Sensing and Leading Edge Blanking** Cycle-by-Cycle current limiting is offered in OB2354 current mode PWM control. The switch current is detected by a sense resistor into the sense pin. An internal leading edge blanking circuit chops off the sensed voltage spike at initial internal power MOSFET on state due to snubber diode reverse recovery and surge gate current of internal power MOSFET so that the external RC filtering on sense input is no longer needed. The current limiting comparator is disabled and cannot turn off the internal power MOSFET during the blanking period. The PWM duty cycle is determined by the current sense input voltage and the FB input voltage.

• Internal Synchronized Slope Compensation

Built-in slope compensation circuit adds voltage ramp onto the current sense input voltage for PWM generation. This greatly improves the close loop stability at CCM and prevents the sub-harmonic oscillation and thus reduces the output ripple voltage.

• Drive

The internal power MOSFET in OB2354 is driven by a dedicated gate driver for power switch control. Too weak the gate drive strength results in higher conduction and switch loss of MOSFET while too strong gate drive results the compromise of EMI



A good tradeoff is achieved through the

built-in totem pole gate design with right output strength and dead time control. The low idle loss and good EMI system design is easier to achieve with this dedicated control scheme.

In addition to the gate drive control scheme mentioned, the gate drive strength can also be adjusted externally by a resistor connected between VDD and VDDG, the falling edge of the Drain output can be well controlled. It provides great flexibility for system EMI design.

• Protection Controls

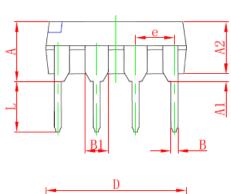
Good power supply system reliability is achieved with its rich protection features including Cycle-by-Cycle current limiting (OCP), Over Load Protection (OLP) and over voltage clamp, Under Voltage Lockout on VDD (UVLO). With On-Bright Proprietary technology, the OCP is line voltage compensated to achieve constant output power limit over the universal input voltage range.

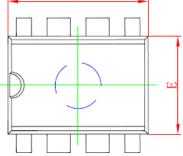
At overload condition when FB input voltage exceeds power limit threshold value for more than TD_PL, control circuit reacts to shut down the switcher. Switcher restarts when VDD voltage drops below UVLO limit.

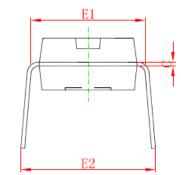
VDD is supplied by transformer auxiliary winding output. It is clamped when VDD is higher than 30V. The output of OB2354 is shut down when VDD drops below UVLO_ON limit and Switcher enters power on start-up sequence thereafter.



PACKAGE MECHANICAL DATA 8-Pin Plastic DIP







Com La L	Dimensions In Millimeters		Dimensions In Inches			
Symbol	Min	Max	Min	Max		
А	3. 710	4. 310	0. 146	0. 170		
A1	0. 510		0. 020			
A2	3. 200	3. 600	0. 126	0. 142		
В	0. 380 0. 570 0. 015 1. 524 (BSC) 0. 06		0.015	0. 022		
B1			0.060 (BSC)			
С	0. 204	0.360	0.008	0.014		
D	9.000	9. 400	0.354	0. 370		
E	6.200	6.600	0. 244	0. 260		
E1	7. 320	7. 920	0. 288	0. 312		
е	2. 540 (BSC)		0.100	(BSC)		
L	3.000	3.600	0. 118	0. 142		
E2	8. 400	9.000	0. 331	0. 354		



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